

Data sheet acquired from Harris Semiconductor

SCHS187C

January 1998 - Revised July 2003

CD54/74HC533, CD54/74HCT533, CD54/74HC563, CD74HCT563

High-Speed CMOS Logic Octal Inverting Transparent Latch, Three-State Outputs

Features

- Common Latch-Enable Control
- Common Three-State Output Enable Control
- Buffered Inputs
- · Three-State Outputs
- . Bus Line Driving Capacity
- Typical Propagation Delay = 13ns at V_{CC} = 5V, $C_L = 15pF$, $T_A = 25^{\circ}C$ (Data to Output)
- Fanout (Over Temperature Range)
 - Standard Outputs........... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at $V_{CC} = 5V$
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, $V_{IL} = 0.8V (Max), V_{IH} = 2V (Min)$
 - CMOS Input Compatibility, $I_I \le 1 \mu A$ at V_{OI} , V_{OH}

Description

The 'HC533, 'HCT533, 'HC563, and CD74HCT563 are high-speed Octal Transparent Latches manufactured with silicon gate CMOS technology. They possess the low power consumption of standard CMOS integrated circuits, as well as the ability to drive 15 LSTTL devices.

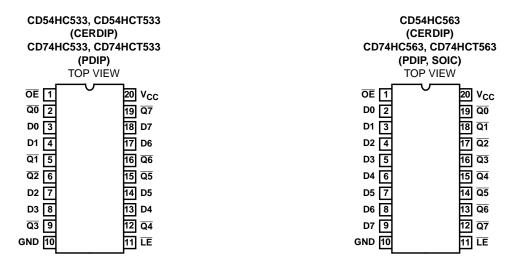
The outputs are transparent to the inputs when the latch enable (\overline{LE}) is high. When the latch enable (\overline{LE}) goes low the data is latched. The output enable (\overline{OE}) controls the three-state outputs. When the output enable (\overline{OE}) is high the outputs are in the high impedance state. The latch operation is independent of the state of the output enable.

The 'HC533 and 'HCT533 are identical in function to the 'HC563 and CD74HCT563 but have different pinouts. The 'HC533 and 'HCT533 are similar to the 'HC373 and 'HCT373; the latter are non-inverting types.

Ordering Information

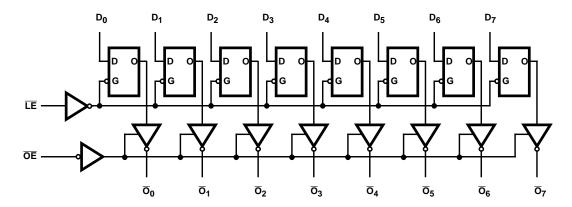
PART NUMBER	TEMP. RANGE (^O C)	PACKAGE
CD54HC533F3A	-55 to 125	20 Ld CERDIP
CD54HC563F3A	-55 to 125	20 Ld CERDIP
CD54HCT533F3A	-55 to 125	20 Ld CERDIP
CD74HC533E	-55 to 125	20 Ld PDIP
CD74HC563E	-55 to 125	20 Ld PDIP
CD74HC563M	-55 to 125	20 Ld SOIC
CD74HCT533E	-55 to 125	20 Ld PDIP
CD74HCT563E	-55 to 125	20 Ld PDIP
CD74HCT563M	-55 to 125	20 Ld SOIC

Pinouts



Functional Block Diagram

HC/HCT533



TRUTH TABLE

OUTPUT ENABLE	LATCH ENABLE	DATA	Q OUTPUT
L	Н	Н	L
L	Н	L	Н
L	L	I	Н
L	L	h	L
Н	X	X	Z

H = High Voltage Level, L = Low Voltage Level, X = Don't Care, Z = High Impedance State, I = Low voltage level one set-up time prior to the high to low latch enable transition, h = High voltage level one set-up time prior to the high to low latch enable transition.

Absolute Maximum Ratings

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (oC/W)
E (PDIP) Package	. 69
M (SOIC) Package	
Maximum Junction Temperature	
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range, T_A 55 0 C to 125 0 C Supply Voltage Range, V_{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS		25°C			-40°C T	O 85°C	-55°C TO 125°C				
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS		
HC TYPES														
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V		
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V		
				6	4.2	-	-	4.2	-	4.2	-	V		
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V		
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V		
				6	-	-	1.8	-	1.8	-	1.8	V		
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V		
Voltage CMOS Loads		V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V		
		-	-0.02	6	5.9	-	-	5.9	-	5.9	-	V		
High Level Output	1		-6	4.5	3.98	-	-	3.84	-	3.7	-	V		
Voltage TTL Loads			-7.8	6	5.48	1	1	5.34	-	5.2	-	V		
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V		
Voltage CMOS Loads		V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V		
000 20000			0.02	6	-	-	0.1	-	0.1	-	0.1	V		
Low Level Output	1		6	4.5	-	-	0.26	-	0.33	-	0.4	V		
Voltage TTL Loads			7.8	6	-	-	0.26	Ī	0.33	-	0.4	V		
Input Leakage Current	Ι _Ι	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА		
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-		8	-	80	-	160	μА		

DC Electrical Specifications (Continued)

			ST ITIONS			25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Three-State Leakage Current	-	V _{IL} or V _{IH}	V _O = V _{CC} or GND	6	-	-	±0.5	-	±5	-	±10	μА
HCT TYPES	•		•		•		•		•	•	•	
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} to GND	-	5.5	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Three-State Leakage Current	-	V _{IL} or V _{IH}	V _O = V _{CC} or GND	5.5	-	-	±0.5	-	±5	-	±10	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS				
D0 - D7	0.15				
ΙΕ	0.30				
ŌĒ	0.55				

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360 μA max at $25^{o}C.$

^{2.} For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

Prerequisite For Switching Specifications

		TEST	V _{CC}		25°C		-40°C T	O 85°C	-55°C T	O 125 ⁰ C			
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS		
HC TYPES													
LE Pulse Width	t _W	-	2	80	-	-	100	-	120	-	ns		
			4.5	16	-	-	20	-	24	-	ns		
			6	14	-	-	17	-	20	-	ns		
Set-up Time Data to LE	t _{SU}	-	2	50	-	-	65	-	75	-	ns		
			4.5	10	-	-	13	-	15	-	ns		
			6	9	-	-	11	-	13	-	ns		
Hold Time, Data to LE	t _H	-	2	35	-	-	45	-	55	-	ns		
(533)			4.5	7	-	-	9	-	11	-	ns		
			6	6	-	-	8	-	7	-	ns		
Hold Time, Data to LE	t _H	-	2	4	-	-	4	-	4	-	ns		
(563)			4.5	4	-	-	4	-	4	-	ns		
			6	4	-	-	4	-	4	-	ns		
HCT TYPES		•							•				
LE Pulse Width	t _w	-	4.5	16	-	-	20	-	24	-	ns		
Set-up Time Data to LE	t _w	-	4.5	10	-	-	13	-	15	-	ns		
Hold Time, Data to LE (533)	t _H	-	4.5	8	-	-	10	-	12	-	ns		
Hold Time, Data to LE (563)	t _H	-	4.5	5	-	-	5	-	5	-	ns		

Switching Specifications Input t_p , $t_f = 6ns$

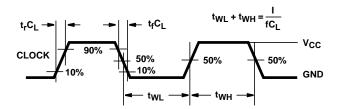
		TEST		25°C		-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES								
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	165	205	250	ns
Data to Qn (HC533)			4.5	-	33	41	50	ns
,			6	-	28	35	43	ns
		C _L = 15pF	5	13	-	-	-	ns
Propagation Delay, Data to Qn (HC563)	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	150	190	225	ns
			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C _L = 15pF	5	12	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	175	220	265	ns
LE to Qn (HC533)			4.5	-	35	44	53	ns
(,			6	-	30	37	45	ns
		C _L = 15pF	5	14	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	165	205	250	ns
LE to Qn (HC563)			4.5	-	33	41	50	ns
			6	-	28	35	43	ns
		C _L = 15pF	5	13	-	-	-	ns

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST		25	°c	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
Enable Times	t _{PZH} , t _{PZL}	C _L = 50pF	2	-	150	190	225	ns
(HC533)			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C _L = 15pF	5	12	-	-	-	ns
Disable Times	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	150	190	225	ns
(HC533)			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C _L = 15pF	5	12	-	-	-	ns
Enable and Disable Times	t _{PZH} , t _{PZL} ,	C _L = 50pF	2	-	150	190	225	ns
(HC563)	t _{PHZ} , t _{PLZ}		4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		C _L = 15pF	5	12	-	-	-	ns
Input Capacitance	Cl	-	-	-	10	10	10	pF
Three-State Output Capacitance	CO	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	42	-	-	-	pF
HCT TYPES								
Propagation Delay, Data to Qn	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	34	43	51	ns
(HC/HCT533)		C _L = 15pF	5	14	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	30	38	45	ns
Data to Qn (HC/HCT563)		C _L = 15pF	5	12	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	ı	38	48	57	ns
LE to Qn (HC/HCT533)		C _L = 15pF	5	16	-	-	-	ns
Propagation Delay,	t _{PZL} , t _{PZH}	C _L = 50pF	4.5	-	35	44	53	ns
LE to Qn (HC/HCT563)		C _L = 15pF	5	14	-	-	-	ns
Enable Times	t _{PLZ} , t _{PZH}	C _L = 50pF	4.5	-	35	44	53	ns
(HC/HCT533)		C _L = 15pF	5	14	-	-	-	ns
Disable Times	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	30	38	45	ns
(HC/HCT533)		C _L = 15pF	5	12	-	-	-	ns
Enable and Disable Times	t _{PZH} , t _{PZL} ,	C _L = 50pF	4.5	-	35	44	53	ns
(HC/HCT563)	t _{PHZ} , t _{PLZ}	C _L = 15pF	5	14	-	-	-	ns
Input Capacitance	C _I	-	-	-	10	10	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	42	-	-	-	pF

- 3. $\ensuremath{\text{C}_{\text{PD}}}$ is used to determine the no-load dynamic power consumption, per latch.
- 4. P_D (total power per latch) = C_{PD} V_{CC}² f_i + Σ C_L V_{CC}² f_o where f_i = Input Frequency, f_o = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

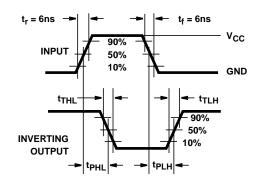


FIGURE 3. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

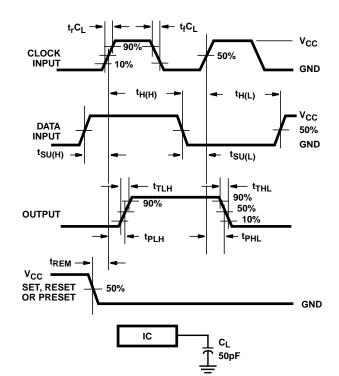
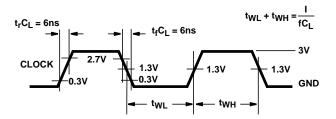


FIGURE 5. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f $_{MAX}$, input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

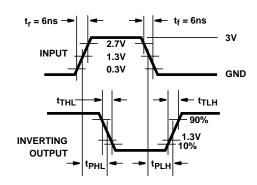


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

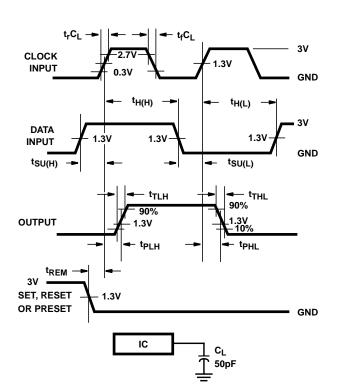
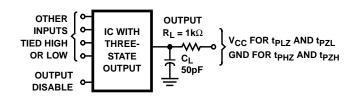


FIGURE 6. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

Test Circuits and Waveforms (Continued) – 6ns 6ns 3V V_{CC} OUTPUT OUTPUT 90% **DISABLE** 50% DISABLE 10% 0.3 GND GND t_{PZL} → - t_{PLZ} → t_{PZL} ► t_{PLZ} → **OUTPUT LOW** OUTPUT LOW 50% TO OFF TO OFF 1.3V 10% 10% ◆ t_{PHZ} ◆ - t_{PZH} · t_{PHZ} → tpzh -90% 90% **OUTPUT HIGH OUTPUT HIGH** 50% TO OFF TO OFF 1.3V OUTPUTS **OUTPUTS OUTPUTS OUTPUTS OUTPUTS OUTPUTS ENABLED** ENABLED **DISABLED ENABLED** DISABLED **ENABLED**

FIGURE 7. HC THREE-STATE PROPAGATION DELAY WAVEFORM

FIGURE 8. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 9. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
5962-8606201RA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8606201RA CD54HC563F3A
5962-8681301RA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8681301RA CD54HC533F3A
CD54HC533F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8681301RA CD54HC533F3A
CD54HC533F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8681301RA CD54HC533F3A
CD54HC563F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8606201RA CD54HC563F3A
CD54HC563F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8606201RA CD54HC563F3A
CD54HCT533F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54HCT533F3A
CD54HCT533F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54HCT533F3A
CD74HC533E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC533E
CD74HC533E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC533E
CD74HC563E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC563E
CD74HC563E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC563E
CD74HCT533E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT533E
CD74HCT533E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT533E
CD74HCT563E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT563E
CD74HCT563E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT563E
CD74HCT563M	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT563M
CD74HCT563M.A	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT563M

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

PACKAGE OPTION ADDENDUM

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(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD54HC533, CD54HC563, CD54HCT533, CD74HC533, CD74HC563, CD74HCT533:

Catalog: CD74HC533, CD74HC563, CD74HCT533

Military: CD54HC533, CD54HC563, CD54HCT533

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

• Military - QML certified for Military and Defense Applications

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC533E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HC533E.A	N	PDIP	20	20	506	13.97	11230	4.32
CD74HC563E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HC563E.A	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT533E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT533E.A	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT563E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT563E.A	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT563M	DW	SOIC	20	25	507	12.83	5080	6.6
CD74HCT563M.A	DW	SOIC	20	25	507	12.83	5080	6.6

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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